NSN 5962-01-364-8001

Memory Microcircuit - Page 1 of 1

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Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Vsds mh60g gr e/i fscm 7s976

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Hi-performance mos

Case Outline Source And Designator:

D-8 mil-m-38510

Terminal Surface Treatment:

Solder

Product Name:

262, 144-word by 4-bit dynamic random-access memory

Voltage Rating And Type Per Characteristic:

-5.0 volts applied and 5.0 volts applied

Time Rating Per Chacteristic:

45.00 nanoseconds access and 150.00 nanoseconds access

Memory Device Type:

Ram

Terminal Type And Quantity:

20 printed circuit

Specification Data:

96906-mil-std-883 government standard

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0